

N-Channel JFET RF Amplifier

BF256B

Features

- This Device is Designed for VHF / UHF Amplifiers
- Sourced from Process 50
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

ABSOLUTE MAXIMUM RATINGS

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

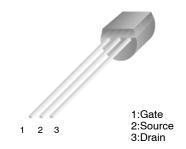
Symbol	Parameter	Value	Unit
V_{DG}	Drain-Gate Voltage	30	V
V _{GS}	Gate-Source Voltage	-30	V
I _{GF}	Forward Gate Current	10	mA
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

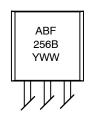
Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P_{D}	Total Device Dissipation at $T_A = 25^{\circ}C$	350	mW
	Derate Above 25°C	2.8	mW/°C



TO-92-3 CASE 135AN

MARKING DIAGRAM



A BF256B Y WW Assembly SiteSpecific Device CodeYear of Production

= Work Week Number

ORDERING INFORMATION

Device	Package	Shipping
BF256B	TO-92-3	10,000 Bulk/Bag

ELECTRICAL CHARACTERISTICS Values are at $T_A = 25$ °C unless otherwise noted.

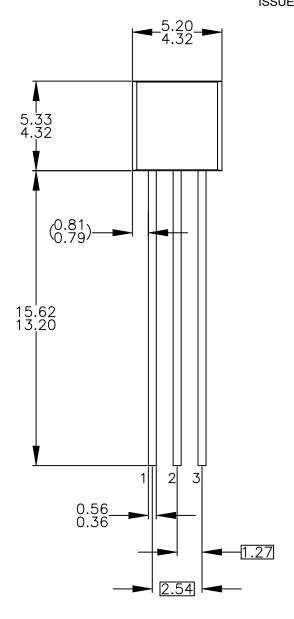
Symbol	Parameter	Conditions	Min	Max	Unit
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$V_{DS} = 0$, $I_{G} = 1 \mu A$	-30	_	V
V_{GS}	Gate-Source Voltage	$V_{DS} = 15 \text{ V}, I_D = 200 \mu\text{A}$	-0.5	-7.5	V
V _{GS} (off)	Gate-Source Cut-Off Voltage	V _{DS} = 15 V, I _D = 10 nA	-0.5	-8.0	V
I _{GSS}	Gate Reverse Current	$V_{GS} = -20 \text{ V}, V_{DS} = 0$	_	-5	nA
I _{DSS}	Zero-Gate Voltage Drain Current	V _{DS} = 15 V, V _{GS} = 0	6	13	mA
gfs	Common Source Forward Transconductance	V _{DS} = 15 V, V _{GS} = 0,f = 1 kHz	4.5	-	mmhos

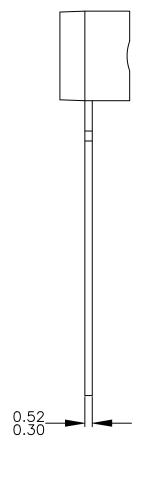
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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TO-92 3 4.825x4.76 CASE 135AN ISSUE O

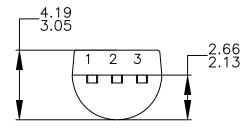
DATE 31 JUL 2016





NOTES: UNLESS OTHERWISE SPECIFIED

- DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS. A)
- ALL DIMENSIONS ARE IN MILLIMETERS.
 DRAWING CONFORMS TO ASME Y14.5M—2009.



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